Panasonic

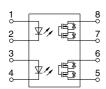
c**PL**us

Normally closed (2 Form B)
DIP6-pin type
Low on-resistance with
400V load voltage

PhotoMOS® HE 2 Form B (AQW454)



mm inch



RoHS compliant

FEATURES

- 1. 2 Form B (Normally-closed) type
 Has been realized thanks to the built-in
 MOSFET processed by our proprietary
 method, DSD (Double-diffused and
 Selective Doping) method.
- 2. Applicable for 2 Form B use as well as two independent 1 Form B use.
- 3. Controls low-level analog signals PhotoMOS feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.
- 4. High sensitivity and low onresistance

Can control max. 0.16 A load current with 5 mA input current. Low on-resistance of Typ. 11 Ω . (in case of using only 1 channel)

5. Low-level off state leakage current of max. 1 μA

TYPICAL APPLICATIONS

- Security equipment
- High-speed inspection machine
- Measuring instruments
- Telecommunication equipment
- Sensing equipment

TYPES

| | Output rating* | | | | Par | | | | |
|-------------------|----------------|---------|----------|--|---------|----------------------------------|----------------------------------|--|---------------|
| | | | Package | Through hole terminal Surface-mount terminal | | | Packing quantity | | |
| | Load Load | Load | гаскауе | Tube packing style | | Tape and reel packing style | | | |
| | voltage | current | | | | Picked from the 1/2/3/4-pin side | Picked from the 5/6/7/8-pin side | Tube | Tape and reel |
| AC/DC dual use | 400 V | 120 mA | DIP8-pin | AQW454 | AQW454A | AQW454AX | AQW454AZ | 1 tube contains: 50 pcs. 1 batch contains: 500 pcs. | 1,000 pcs |

^{*}Indicate the peak AC and DC values.

Note: The surface mount terminal indicator "A" and the packing style indicator "X" or "Z" are not marked on the device.

RATING

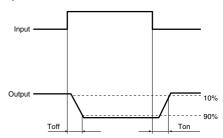
1. Absolute maximum ratings (Ambient temperature: $25^{\circ}C$ $77^{\circ}F$)

| Item | | Symbol | AQW454(A) | Remarks | |
|-------------------------|---------------------------------------|----------------|-----------------------------|--|--|
| Input | LED forward current | l _F | 50 mA | | |
| | LED reverse voltage | VR | 5 V | | |
| | Peak forward current | IFP | 1 A | f = 100 Hz, Duty factor = 0.1% | |
| | Power dissipation | Pin | 75 mW | | |
| | Load voltage (peak AC) V _L | | 400 V | | |
| Output | Continuous load current | lı. | 0.12 A (0.16 A) | A connection: Peak AC, DC (): in case of using only 1 channel | |
| • | Peak load current | Ipeak | 0.36 A | A connection: 100 ms (1 shot), V _L = DC | |
| | Power dissipation | Pout | 800 mW | | |
| Total power dissipation | | PT | 850 mW | | |
| I/O isolation voltage | | Viso | 1,500 Vrms | | |
| Ambient emperature | Operating | Topr | -40 to +85°C -40 to +185°F | (Non-icing at low temperatures) | |
| | Storage | Tstg | -40 to +100°C -40 to +212°F | | |

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

| Item | | | | AQW454(A) | Condition | |
|-----------------------------|--|---------|-------|--|--|--|
| Input | LED operate (OFF) current | Typical | Foff | 0.9 mA | IL = Max. | |
| | LED operate (OFF) current | Maximum | IFoff | 3 mA | IL = Max. | |
| | LED reverse (ON) current | Minimum | Fon | 0.4 mA | IL = Max. | |
| | LED reverse (ON) current | Typical | I Fon | 0.8 mA | IL = IVIAX. | |
| | LED dropout voltage | Typical | VF | 1.25 V (1.14 V at I _F = 5 mA) | I _F = 50 mA | |
| | LED dropout voltage | Maximum |] VF | 1.5 V | IF = 50 IIIA | |
| Output | 0 | Typical | | 11 Ω | IF = 0 mA | |
| | On resistance | Maximum | Ron | 16 Ω | I∟ = Max. Within 1 s | |
| | Off state leakage current | Maximum | ILeak | 1 μΑ | $I_F = 5 \text{ mA}$ $V_L = \text{Max}$. | |
| | Operate (OFF) time* | Typical | Toff | 1.2 ms | I _F = 0 mA → 5 mA | |
| | Operate (OFF) time | Maximum | loff | 2 ms | I∟ = Max. | |
| - , | Reverse (ON) time* | Typical | Ton | 0.36 ms | I _F = 5 mA → 0 mA | |
| Transfer characteristics | neverse (ON) time | Maximum | lon | 1 ms | I∟ = Max. | |
| | I/O conscitones | Typical | | 0.8 pF | f = 1 MHz | |
| | I/O capacitance | Maximum | Ciso | 1.5 pF | V _B = 0 V | |
| | Initial I/O isolation resistance Minimum | | Riso | 1,000 ΜΩ | 500 V DC | |

*Operate/Reverse time



3. Recommended operating conditions (Ambient temperature: 25°C 77°F)

Please use under recommended operating conditions to obtain expected characteristics.

| | Item | Symbol | Number of used channels | Min. | Max. | Unit |
|-----------|-------------------------|--------|-------------------------|------|--------------|------|
| | LED current | lF | | 5 | 30 | mA |
| AQW454(A) | Load voltage (Peak AC) | V∟ | | _ | 320 | ٧ |
| | Continuous load current | lı | 1ch 2ch | _ | 0.16 0.12 | Α |

■ These products are not designed for automotive use.

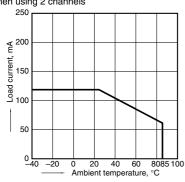
If you are considering to use these products for automotive applications, please contact your local Panasonic Corporation technical representative.

REFERENCE DATA

1. Load current vs. ambient temperature characteristics

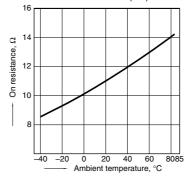
Allowable ambient temperature: -40 to +85°C

When using 2 channels



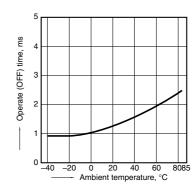
2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 5 and 6, 7 and 8; LED current: 0 mA; Load voltage: 400 V (DC); Continuous load current: 120 mA (DC)



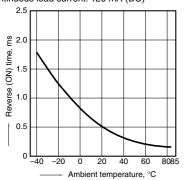
3. Operate (OFF) time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: 400 V (DC); Continuous load current: 120 mA (DC)



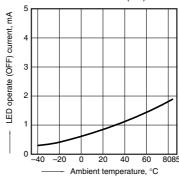
4. Reverse (ON) time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: 400 V (DC); Continuous load current: 120 mA (DC)

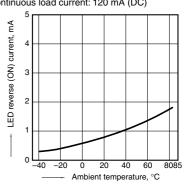


5. LED operate (OFF) current vs. ambient temperature characteristics Load voltage: 400 V (DC);

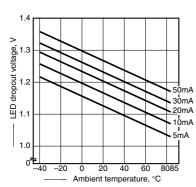
Continuous load current: 120 mA (DC)



6. LED reverse (ON) current vs. ambient temperature characteristics Load voltage: 400 V (DC); Continuous load current: 120 mA (DC)

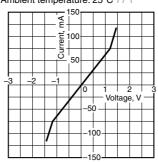


7. LED dropout voltage vs. ambient temperature characteristics LED current: 5 to 50 mA



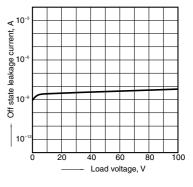
 Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 5 and 6, 7 and 8; Ambient temperature: 25°C 77°F



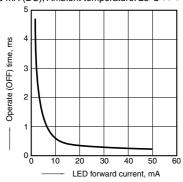
 Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Ambient temperature: 25°C 77°F



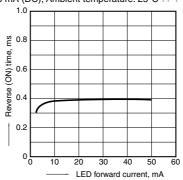
10. Operate (OFF) time vs. LED forward current characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Load voltage: 400 V (DC); Continuous load current: 120 mA (DC); Ambient temperature: 25°C 77°F



11. Reverse (ON) time vs. LED forward current characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Load voltage: 400 V (DC); Continuous load current: 120 mA (DC); Ambient temperature: 25°C 77°F



12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Frequency: 1 MHz; Ambient temperature: 25°C 77°F

Applied voltage, V

Output capacitance, pF

10 20 30 40 50

"PhotoMOS", "PhotoMOS" and "PHOTOMOS" are registered trademarks of Panasonic Corporation.

Please contact

Panasonic Corporation

Electromechanical Control Business Division

■ 1006, Oaza Kadoma, Kadoma-shi, Osaka 571-8506, Japan industrial.panasonic.com/ac/e/



©Panasonic Corporation 2017

^{*}Recognized in Japan, the United States, all member states of European Union and other countries.